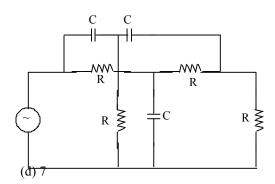
## Q.1 œ Q.30 Carry One Mark Each

The minimum number of equations required to analyze the circuit shown in

1.

Fig.Q.1 is



(a) 3

- (b) 4
- (c) 6
- 2. A source of angular frequency 1 rad/sec has a source impedance consisting of 1& resistance in series with 1 H inductance. The load that will obtain the maximum power transfer is
  - (a) 1 & resistance
  - (b) 1 & resistance in parallel with 1 H inductance
  - (c) 1 & resistance in series with 1 F capacitor
  - (d) 1 & resistance in parallel with 1 F capacitor
- 3. A series RLC circuit has a resonance frequency of 1 kHz and a quality factor Q = 100. If each R, L and C is doubled from its original value, the new Q of the circuit is
  - (a) 25

(b) 50

- (c) 100
- (d) 200

4. The Laplace transform of i(t) is given by Is()

$$= \underbrace{\begin{pmatrix} 2 \\ + \end{pmatrix}}_{s=1, s}$$

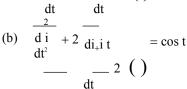
As t %  $\Box$ , the value of i(t) tends to

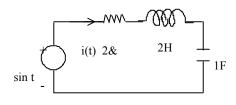
(a) 0

(b) 1

- (c) 2
- (d) □
- 5. The differential equation for the current i(t) in the circuit of Figure Q.5 is

(a) 
$$2_2 + \frac{d^2 i}{2}$$
  $\frac{di_+ i t}{dt}$  ( ) = sint





(c) 
$$\begin{array}{ccc} & \overset{2}{di} & & \underline{\quad} di_{+}i t \\ & 2_{2}+2 & & \\ & dt & dt \end{array}$$

- **GATE EC 2003** n-type silicon is obtained by doping silicon with 6. (a) Germanium (b) Aluminum (c) Boron (d) Phosphorus 7. The bandgap of silicon at 300 K is (a) 1.36 eV (b) 1.10 eV (c) 0.80 eV (d) 0.67 eV The intrinsic carrier concentration of silicon sample of 300 K is 1.5 ·10<sup>16</sup>/m³. If 8. after doping, the number of majority carriers is  $5 \cdot 10^{20}$ /m<sup>3</sup>, the minority carrier density is (a)  $4.50 \cdot 10^{11}/\text{m}^3$  (b)  $3.33 \cdot 10^4/\text{m}^3$ (c)  $5.00 \cdot 10^{20} / \text{m}^3$  (d)  $3.00 \cdot 10^{-5} / \text{m}^3$ 9. Choose proper substitutes for X and Y to make the following statement correct Tunnel diode and Avalanche photodiode are operated in X bias and Y bias respectively. (a) X: reverse, Y: reverse (b) X: reverse, Y: forward (c) X: forward, Y: reverse (d) X: forward, Y: forward 10. For an n-channel enhancement type MOSFET, if the source is connected at a higher potential than that of the bulk (i.e. VsB > 0), the threshold voltage VT of the MOSFET will
- 11. Choose the correct match for input resistance of various amplifier configurations shown below.

Configuration Input resistance
CB: Common Base LO: Low
CC: Common Collector MO: Moderate

CE: Common Emitter HI: High

(a) CB-LO, CC-MO, CE-HI

(b) CB-LO, CC-HI, CE-MO (d) CB-HI, CC-LO, CE-MO

(b) decrease

(d) increase

- 12. The circuit shown in figure is best described as a
  - (a) bridge rectifier

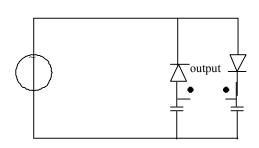
(a) remain unchanged

(c) change polarity

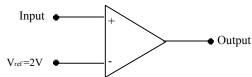
- (b) ring modulator
- (c) frequency discriminatory

(c) CB-MO, CC-HI, CE-LO

(d) voltage doubler



13. If the input to the ideal comparator shown in figure is a sinusoidal signal of 8V (peak to peak) without any DC component, then the output of the comparator has a duty cycle of



- (a)  $\frac{1}{2}$
- (b)  $\frac{1}{3}$

- (c)  $\frac{1}{6}$
- (d)  $\frac{q}{12}$

14. If the differential voltage gain and the common mode voltage gain of a differential amplifier are 48 dB and 2 dB respectively, then its common mode rejection ratio is

- (a) 23 dB
- (b) 25 dB
- (c) 46 dB
- (d) 50 dB

15. Generall the gain of a transistor amplifier falls at high frequencies due to the

- (a) internal capacitances of the device
- (b) coupling capacitor at the input
- (c) skin effect
- (d) coupling capacitor at the output

16. The number of distinct Boolean expression of 4 variables is

(a) 16

- (b) 256
- (c) 1024
- (d) 65536

17. The minimum number of comparators required to build an 8 it flash ADC is

(a) 8

(b) 63

- (c) 255
- (d) 256

18. The output of the 74 series of TTL gates is taken from a BJT in

- (a) totem pole and common collector configuration
- (b) either totem pole or open collector configuration
- (c) common base configuration
- (d) common collector configuration

19. Without any additional circuitry, an 8:1 MUX can be used to obtain

- (a) some but not all Boolean functions of 3 variables
- (b) all function of 3 variables but none of 4 variables
- (c) all functions of 3 variables and some but not all of 4 variables
- (d) all functions of 4 variables

- 20. A 0 to 6 counter consists of 3 flip flops and a combination circuit of 2 input gate(s). The combination circuit consists of
  - (a) one AND gate

- (b) one OR gate
- (c) one AND gate and one OR gate
- (d) two AND gates
- 21. The Fourier series expansion of a real periodic signal with fundamental frequency

fo is given by g  $t_p$ ( ) =  $\int_{n=\square\square} c \ e_n 2 \square_s it$  is given that  $C_3 = 3 + j5$ . Then  $C_{-3}$  is

- (a) 5+j3
- (b) -3-i5
- (c) -5+j3
- (d) 3-j5
- 22. Let x(t) be the input to a linear, time-invariant system. The required output is 4x(t-2). The transfer function of the system should be
  - (a) 4  $^{4j f}_{e}$
- (b) 2 e□ 8□
- (c) 4 e□ 4□
- (d)  $2 e^8 \square$

23. A sequence x(n) with the z-transform  $X(z) = z^4 + z^2 \square$ 

z□4 is applied as

 $2z+\Box 2$  3

an input to a linear, time-invariant system with the impulse response  $h(n) = 2^{TM}(n-3)$  where

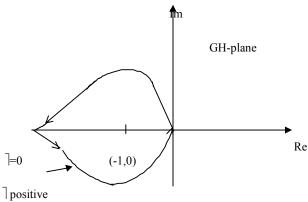
$$\mathsf{TM}\left(\ \right) = \overset{\mathsf{A}}{\mathsf{A}}\overset{\mathsf{A}}{\mathsf{A}}, \ \ n = 0$$

Õ0, otherwise

The output at n = 4 is

(a) -6

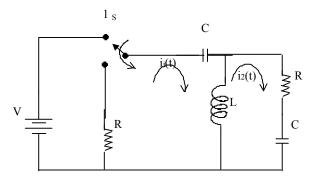
- (b) zero
- (c) 2
- (d) -4
- 24. Figure shows the Nyquist plot of the open-loop transfer function G(s)H(s) of a system. If G(s)H(s) has one right hand pole, the closed loop system is



- (a) always stable
- (b) unstable with one closed loop right hand pole
- (c) unstable with two closed loop right hand poles
- (d) unstable with three closed loop right hand poles

25.	A PD controller is used to compensate a system. Compared to the uncompensated system, the compensated system has						
	(a) a higher type number	r	(b) red	uced damping	5		
	(c) higher noise amplifi	cation	(d) larg	ger transient o	vershoot		
26.	The input to a coherent detector is DSB-SC signal plus noise. The noise at the detector output is						
	(a) the in-phase component			(b) the quadrature-component			
	(c) zero	(d) the	(d) the envelope				
27.	The noise at the input to an ideal frequency detector is white. The detector is operating above threshold. The power spectral density of the noise at the output is						
	(a) raised cosine	(b) flat	(c) par	abolic	(d) Gaussian		
28.	At a given probability of error, binary coherent FSK is inferior to binary coherent PSK by						
	(a) 6 dB	(b) 3 dB	(c) 2 d	В	(d) 0 dB		
29.	The unit of $\square \cdot H$ is						
	(a) Ampere			(b) Ampere/meter			
	(c) Ampere/meter <sup>2</sup>		(d) Am	npere-meter			
30.	The depth of penetration of electromagnetic wave in a medium having conductivity $\int$ at a frequency of 1 MHz is 25 cm. The depth of penetration at a frequency of 4 MHz will be						
	(a) 6.25 cm	(b) 12.50 cm	(c) 50.	00 cm	(d) 100.00 cm		
	Ç	0.31 œ Q.90 Carry T	wo Marks Each				
31.	Twelve 1& resistances are used as edges to form a cube. The resistance between two diagonally opposite corners of the cube is						
	(a) <sup>5</sup> &6	(b) <sup>1</sup> &6	(c) <sup>6</sup> &	-	(d) <sup>3</sup> &-		
32.	The current flowing through P cos 4t, where P is	ough the resistance F	in the circuit in fig M=0.				
	(a) (0.18+j0.72)						
	(b) (0.46+j1.90)	W	31 😫 🖁	000	₹ R=3.92&		
	(c) -(0.18+j1.90)	ĺ					
	(d) -(0.192+j0.144)		V=2cos4t ~				

The circuit for Q.33-34 is given in figure. For both the questions, assume that the switch S is in position 1 for a long time and thrown to position 2 at t = 0.



33. At  $t = 0^+$ , the current ii is

- (a)  $\Box V \\ 2R$
- (b) □V R
- (c)  $\Box V$  4R

 $i_1()$ 

(d) zero

34. () ()

and i<sub>2</sub>() respectively. The

I s<sub>1</sub> and I s<sub>2</sub>are the Laplace transforms of

equations for the loop currents  $I s_1()$  and  $I s_2()$  for the circuit shown in figure Q.33-34, after the switch is brought from position 1 to position 2 at t = 0, are

R + L

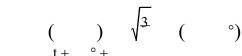
+

 $\Box Ls$ 

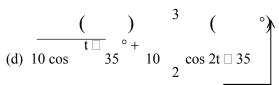
35. An input voltage  $v(t) = 10 2 \cos t + 10^{\circ} + 10 3 \cos 2t + 10^{\circ}$  V is applied to a series combination of resistance R = 1& and an inductance L = 1H. The resulting steady state current i(t) in ampere is



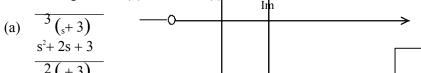
2



- $\frac{1}{55}$   $\frac{10}{2}$   $\cos 2t + 55$ (b) 10 cos
- (c)  $10 \cos t \square 35^{\circ} + 10 \cos 2t + 10^{\circ} \square \tan t$



36. The driving point impedance Z(s) of a network has the pole-zero locations as shown in figure. If Z(0) = 3, then Z(s) is



- s-plane
- $3 \left( _{s} \square 3 \right)$ (c)
- $s^2\square\ 2s\ \square\ 2$ Re (d)  $^{2}(_{s}\square 3)$ **②** œ denotes zero  $_2\,\square\,\,2s\,\square\,\,3$ X € denotes pole
- 37. The impedance parameters  $Z_{11}$  and  $Z_{12}$  of the two-port network in figure are
  - (a)  $Z_{11} = 2.75$ % and  $Z_{12} = 0.25$ %
- 3&

- (b)  $Z_{11} = 3$ & and  $Z_{12} = 0.5$ &
- & 1
- (c)  $Z_{11} = 3$ & and  $Z_{12} = 0.25$ &

1& 1&

(d)  $Z_{11} = 2.25$ & and  $Z_{12} = 0.5$ &

1' 2'

- An n-type silicon bar 0.1 cm long and  $\mu m^2$  in cross-sectional area has a majority 38. carrier concentration of 5 · 10<sup>20</sup>/m³ and the carrier mobility is 0.13m²/V-s at 300K. if the charge of an electron is  $1.6 \cdot 10^{-19}$  coulomb, then the resistance of the bar is
  - (a) 10<sup>6</sup> ohm
- (b) 10<sup>4</sup> ohm
- (c) 10<sup>-1</sup> ohm
- (d)  $10^{-4}$  ohm

2

- 39. The electron concentration in a sample of uniformly doped n-type silicon at 300 K varies linearly from  $10^{17}$ /cm<sup>3</sup> at x = 0 to 6 ·  $10^{16}$ /cm<sup>3</sup> at x = 2 $\mu$ m. Assume a situation that electrons are supplied to keep this concentration gradient constant with time. If electronic charge is 1.6·10<sup>-19</sup> coulomb and the diffusion constant  $D_n = 35 \text{ cm}^2/\text{s}$ , the current density in the silicon, if no electric field is present, is
  - (a) zero

(b) -112 A/cm<sup>2</sup>

(c)  $+1120 \text{ A/cm}^2$ 

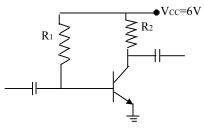
(d) -1112 A/cm<sup>2</sup>

40.

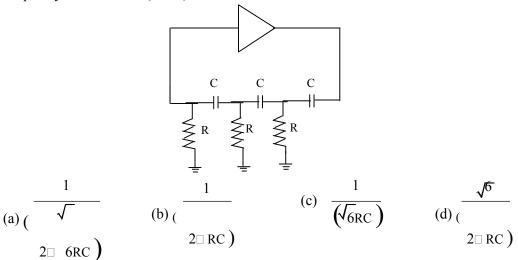
	G	roup 1	Group 2	
	P LED	1	Heavy doping	
	Q Avalanc	he photodiode 2	Coherent radiation	
	R Tunnel d	liode 3	Spontaneous emission	
	S LASER	4	Current gain	
	(a) P @ 1 Q @ 2 R @ 4	S - 3	(b) P @ 2 Q @ 3 R o	e 1 S - 4
	(c) P @ 3 Q @ 4 R @ 1 S	- 2	(d) P & 2 Q & 1 R & 4	4 S - 3
41.	forward bias of 0.1435 of 0.718V. Under the oratio of reverse saturation	V, whereas a certain seconditions stated aboven current in germanium	certain germanium dioc silicon diode requires a for e, the closest approxima n diode to that in silicon o	orward bias ation of the diode is
	(a) 1	(b) 5	(c) $4 \cdot 10^3$	(d) $8 \cdot 10^3$
42.	-	_	gth 5490°A. The energy b k's constant = 6.626·10 <sup>-34</sup> (c) 1.17 eV	
43.	When the gate-to-source voltage (VGS) of a MOSFET with threshold voltag 400mV, working in saturation is 900 mV, the drain current in observed to b mA. Neglecting the channel width modulation effect and assuming that the MOSFET is operating at saturation, the drain current for an applied $V_{\rm GS}$ of 1400 mV is			erved to be 1
	(a) 0.5 mA	(b) 2.0 mA	(c) 3.5 mA	(d) 4.0 mA
44.	diffusion, then the order in fabrication process, is	which they are carried or	is metallization and S at in a standard n-well CMC	OS
	(a) P-Q-R-S	(b) Q-S-R-P	(c) R-P-S-Q	(d) S-R-Q-P
45.	An amplifier without feedback has a voltage gain of 50, input resistance of 1 K& and output resistance of 2.5 K&. The input resistance of the current-shunt negative feedback amplifier using the above amplifier with a feedback factor of 0.2, is			
	(a) <sup>1</sup> K&. 11	(b) <sup>1</sup> K.& 5	(c) 5 K&	(d) 11 K&

Match items in Group 1 with items in Group 2, most suitably.

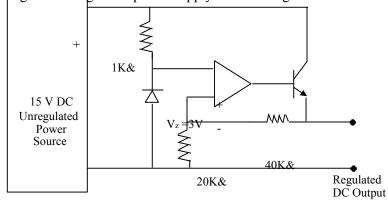
- 46. In the amplifier circuit shown in figure, the values of  $R_1$  and  $R_2$  are such that the transistor is operating at  $V_{ce} = 3V$  and  $I_c = 1.5mA$  when its ® is 150. For a transistor with ® of 200, the operating point  $(V_{ce}I_c)$  is
  - (a) (2V, 2 mA)
  - (b) (3V, 2 mA)
  - (c) (4V, 2 mA)
  - (d) (4V, 1 mA)



47. The oscillator circuit shown in figure has an ideal inverting amplifier. Its frequency of oscillation (in Hz) is



48. The output voltage of the regulated power supply shown in figure is

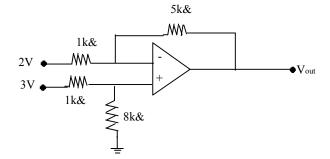


- (a) 3V
- (b) 6V
- (c) 9V
- (d) 12V

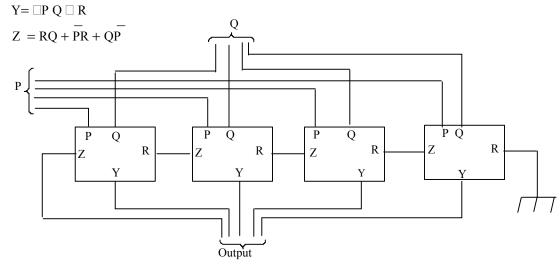
- 49. The action of a JFET in its equivalent circuit can best be represented as a
  - (a) Current Controlled Current Source
  - (b) Current Controlled Voltage Source
  - (c) Voltage Controlled Voltage Source
  - (d) Voltage Controlled Current Source
- 50. If the op-amp in figure is ideal, the output voltage  $V_{\mbox{\tiny out}}$  will be equal to



- (b) 6V
- (c) 14V
- (d) 17V



- 51. Three identical amplifiers with each one having a voltage gain of 50, input resistance of 1 K& and output resistance of 250&, are cascaded. The open circuit voltage gain of the combined amplifier is
  - (a) 49 dB
- (b) 51 dB
- (c) 98 dB
- (d) 102 dB
- 52. An ideal sawtooth voltage waveform of frequency 500 Hz and amplitude 3V is generated by charging a capacitor of 2  $\mu$ F in every cycle. The charging requires
  - (a) constant voltage source of 3 V for 1 ms
  - (b) constant voltage source of 3 V for 2 ms
  - (c) constant current source of 3 mA for 1 ms
  - (d) constant current source of 3 mA for 2 ms
- 53. The circuit shown in figure has 4 boxes each described by inputs P, Q, R and outputs Y, Z with



The circuit acts as a

- (a) 4 bit adder giving P + Q
- (c) 4 bit subtractor-giving Q P
- (b) 4 bit subtractor-giving P Q
- (d) 4 bit adder giving P + Q + R
- 54. If the functions W, X, Y and Z are as follows

$$W = R + P\overline{Q} + R\overline{S}$$

$$X = PQRS + PQS + PQS - - -$$

$$Y = RS PR + PQ + ...$$

$$Z = R + +S PQ + \dots + \dots$$

Then

- (a) W = Z, X = Z (b) W = Z, X = Y
- (c) W = Y
- (d) W = Y = Z
- 55. A 4 bit ripple counter and a 4 bit synchronous counter are made using flip-flops having a propagation delay of 10 ns each. If the worst case delay in the ripple counter and the synchronous counter be R and S respectively, then
  - (a) R = 10 ns, S = 40 ns

(b) R = 40 ns, S = 10 ns

(c) R = 10 ns, S = 30 ns

- (d) R = 30 ns, S = 10 ns
- The DTL, TTL, ECL and CMOS families of digital ICs are compared in the following 56. 4 columns

Fanout is minimum

Power consumption is minimum

Propagation delay is minimum

(P) (Q) (R) (S) DTL DTL TTL**CMOS** TTL **CMOS ECL** DTL **CMOS** ECL TTL TTL

The correct column is

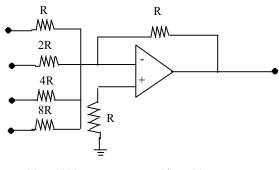
(a) P

- (b) Q
- (c) R
- (d) S

57. The circuit shown in figure is a 4-bit DAC

> The input bits 0 and 1 are represented by 0 and 5 V respectively. The OP AMP is ideal, but all the resistances and the 5V inputs have a tolerance of  $\pm 10\%$ . The specification (rounded to the nearest multiple of 5%) for the tolerance of the DAC is

- (a)  $\pm 35\%$
- (b)  $\pm 20\%$

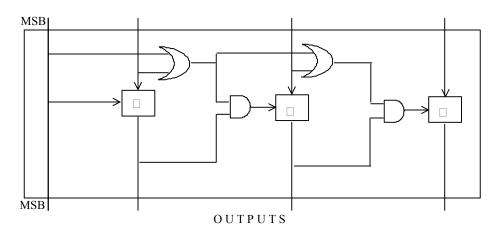


(c) ±10%

(d)  $\pm 5\%$ 

58. The circuit shown in figure converts

INPUTS

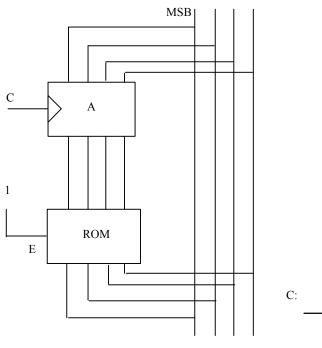


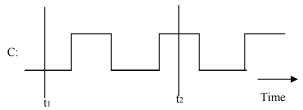
- (a) BCD to binary code
- (c) Excess & 3 to Gray code

- (b) Binary to excess & 3 code
- (d) Gray to Binary code
- 59. In the circuit shown in Figure, A is a parall in, parall -out 4-bit register, which loads at the rising edge of the clock C. The input lines are connected to a 4-bit bus, W. Its output acts as the input to a 16-4 ROM whose output is floating when the enable input E is 0. A partial table of the contents of the ROM is as follows

W

Address	0	2	4	6	8	10	11	14
Data	0011	1111	0100	1010	1011	1000	0010	1000





(a) 0.717

	The clock to the register is shown, and the data on the W bus at time $t_1$ is 0110. The data on the bus at time $t_2$ is					
	(a) 1111	(b) 1011	(c) 1000	(d) 0010		
60.	In an 8085 microprocessor, the instruction CMP B has been executed while the content of the accumulator is less than that of register B. As a result  (a) Carry flag will be set but Zero flag will be reset  (b) Carry flag will be reset but Zero flag will be set  (c) Both Carry flag and Zero flag will be reset  (d) Both Carry flag and Zero flag will be set					
61.	Let X and Y be two statist distributed in the ranges (-1,1) probability that $[Z\delta-2]$ is	Z = X + Y. then the				
	(a) zero	(b) 1 <u> </u>	(c) $\frac{1}{3}$	(d) $\frac{1}{12}$		
62.	Let P be linearity, Q be discrete time system has the $\hat{A}$ ( ) $n = \hat{A}$ ( )	e input-output relationship ε 1 = 0 5 □ 1		item has the		
	r Q.63-64 are given below stem under consideration μF.	•				
63.	Let H(f) denote the frequency response of the RC-LPF. Let f <sub>1</sub> be the highest					
	frequency such that $0 \delta$ (a) 327.8	f δ . ε 0.9. f <sub>1</sub> H ( ) (b) 163.9	5.Then f <sub>1</sub> (in Hz) is (c) 52.2	(d) 104.4		
64.	Let $t_g(f)$ be the group de $t_g(f_2)$ in ms, is	lay function of the given	RC-LPF and $f_2 = 1$	00 Hz. Then		

(b) 7.17

(c) 71.7

(d) 4.505

Data for Q.65  $\times$  66 are given below. Solve the problems and choose the correct answers.

X(t) is a random process with a constant mean value of 2 and the autocorrelation

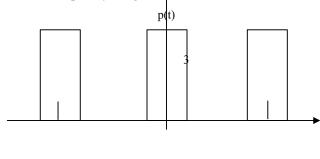
function  $R_x()$   $= 4^* ... e_{\square} |_{+\ddot{y}'}$ 

65. Let X be the Gaussian random variable obtained by sampling the process at  $t = t_i$ 

and let Q() =  $\frac{1}{\sqrt{1}} \frac{Qy}{2}$ 

The probability that  $>x \delta 1$  ÿis

- (a) 1 œ Q(0.5)
- (b) Q(0.5)
- (c)  $Q\Delta \stackrel{\approx}{\rightarrow} \begin{array}{c} & & \\ &$
- (d) 1  $\underset{\square \ Q \ \Delta}{\approx} \frac{}{\checkmark}$ ,  $\underset{\text{42.2 } \Diamond}{}$
- 66. Let Y and Z be the random variables obtained by sampling X(t) at t = 2 and t = 4 respectively. Let  $W = Y \times Z$ . The variance of W is
  - (a) 13.36
- (b) 9.36
- (c) 2.64
- (d) 8.00
- 67. Let  $x(t) = 2\cos(800\Box t) + \cos(1400\Box t)$ . x(t) is sampled with the rectangular pulse train shown in figure. The only spectral components (in kHz) present in the sampled signal in the frequency range 2.  $\clubsuit$  kHz to 3.5 kHz are



-To  $-T_0/6$  0  $T_0/6$   $T_0=10$  -3sec

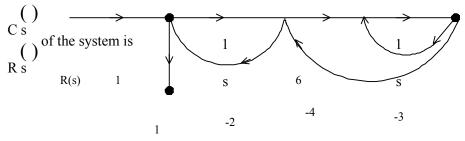
To

(a) 2.7, 3.4

(b) 3.3, 3.6

(c) 2.6, 2.7, 3.3, 3.4, 3.6

- (d) 2.7, 3.3
- 68. The signal flow graph of a system is shown in figure. The transfer function



C(s)

(a) 
$$_{s}^{2}$$
 + 29s + 6

(c) 
$$\frac{\binom{1}{1}}{\binom{1}{2}}$$

(b) 
$$\frac{6s}{2}$$
 (c)  $\frac{\binom{1}{s}}{\frac{s}{s}} = \binom{1}{2}$  (d)  $\frac{\binom{1}{s}}{\frac{s}{s}} = \binom{1}{2}$ 

$$\frac{1}{s} + 29s + 6 = \frac{1}{s} = \frac{29s + 6}{s} = \frac{29s +$$

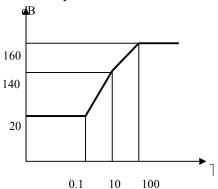
The root locus of the system 69. located at

s + 2 + 3 + 3 has the break-away point

(a) 
$$(-0.5,0)$$

$$(c) (-4,0)$$

- (d)(-0.784,0)
- 70. The approximate Bode magnitude plot of a minimum-phase system is shown in figure. The transfer function of the system is



$$(s + 0.1)^3$$

$$_{7}$$
  $(_{s+0.1})^{3}$ 

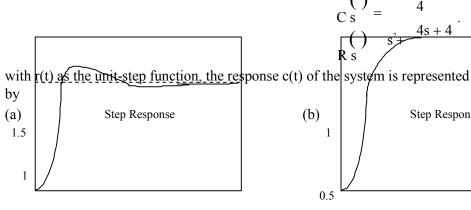
(a) 10 
$$\frac{(s+10)(s+100)}{(s+100)}$$
8 
$$\frac{(s+10)(s+100)}{(s+100)}$$

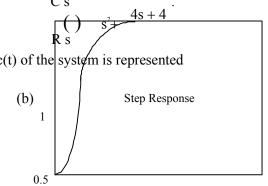
(b) 10 
$$(s+10)(s+100)$$

(c) 10 
$$(s+10)(s+100)$$

(d) 10 
$$(s + \frac{10}{3}) (s + \frac{100}{3})^2$$

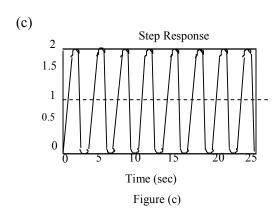
71. A second-order system has the transfer function

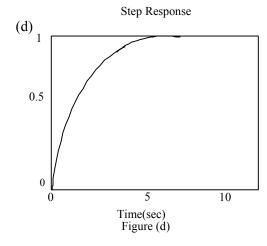




0.5

0 0 0 6 0 2 6 2 4 Time(sec) Time(sec) Figure (b) Figure (a)





- (a) Figure (a)
- (b) Figure (b)
- (c) Figure (c)
- (d) Figure (d)
- 72. The gain margin and the phase margin of a feedback system with

$$() () = \frac{s}{s + 100)^3}$$
 are

- (a)  $0 \text{ dB}, 0^{\circ}$
- (b) □,□
- (c)  $\square$ ,  $0^{\circ}$
- (d)  $88.5 \text{ dB}, \square$
- 73. The zero-input response of a system given by the state-space equation

» tÿ

- »e⁺ÿ
- » t ÿ

- (a)

- (d) ... Ÿ
- 74. A DSB-SC signal is to be generated with a carrier frequency fc = 1MHz using a nonlinear device with the input-output characteristic

- 2)

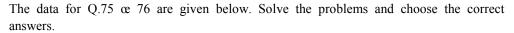
 $A_c \cos 2 \square f t_c + m t$ where m(t) is the message signal. Then the value of Let  $v_i$ = f<sub>c</sub>2 (in MHz) is

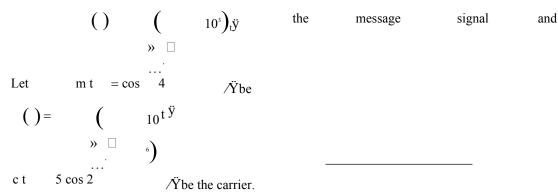
- (a) 1.0
- (b) 0.333

()

- (c) 0.5
- (d) 3.0

78.





75. c(t) and m(t) are used to generate an AM signal. The modulation index of the generated AM signal is 0.5. Then the quantity Total sideband power<sub>is</sub>

Carrier power

 $C_{\scriptscriptstyle \mathsf{min}}$ 

(a) 
$$\frac{1}{2}$$
 (b)  $\frac{1}{4}$  (c)  $\frac{1}{3}$  (d)  $\frac{1}{8}$ 

76. c(t) and m(t) are used to generate an FM signal. If the peak frequency deviation of the generated FM signal is three times the transmission bandwidth of the AM

singal, then the coefficient of the term  $\cos 2^{\circ} \dots \square$ t<sup>ÿ</sup>Ÿ/in the FM signal (in 1008 10 terms of the Bessel coefficients) is (c)  $\frac{5}{2}$   $J_8()$ (b)  $\frac{5}{2}$  J<sub>8</sub>() (a)  $5J_4()$ (d)  $5J_4$ 

77. Choose the correct one from among the alternatives A, B, C, D after matching an item in Group 1 with the most appropriate item in Group 2.

Group 1	Group 2			
P Ring modulator	1 Clock recovery			
Q VCO	2 Demodulation of FM			
R Foster-Seely discriminator	3 Frequency conversion			
S Mixer	4 Summing the two inputs			
	5 Generation of FM			
	6 Generation of DSB-Sc			
(a) P @ 1 Q @ 3 R @ 2 S @ 4	(b) P @ 6 Q @ 5 R @ 2 S @ 3			
(c) P @ 6 Q @ 1 R @ 3 S @ 2	(d) P @ 5 Q @ 6 R @ 1 S @ 3			
A superheterodyne receiver is to operate in the frequency range 550 kHz & 1650				

required capacitance ratio of the local oscillator and I denote the image frequency (in kHz) of the incoming signal. If the receiver is tuned to 700 kHz, then

kHz, with the intermediate frequency of 450 kHz. Let  $R = \frac{max}{2}$  denote the

(a) R = 4.41, I = 1600(b) R = 2.10, I = 1150

(c) 
$$R = 3.0, I = 1600$$
 (d)  $R = 9.0, I = 1150$ 

79.

	(a) 0.768 V	(b) $48 \cdot 10^{-6} V^2$	(c) $12 \cdot 10^{-6} V^2$	(d) 3.072 V			
80.	If Eb' the energy per bit of a binary digital signal, is $10^{-6}$ watt-sec and the one-sided power spectral density of the white noise, $N_0 = 10^{-5}$ W/Hz, then the output SNR of the matched filter is						
	(a) 26 dB	(b) 10 dB	(c) 20 dB	(d) 13 dB			
81.	The input to a linear delta modulator having a step-size $\acute{I}=0.628$ is a sine wave with frequency $f_m$ and peak amplitude $E_m$ . If the sampling frequency $f_s=40$ kHz, the combination of the sine-wave frequency and the peak amplitude, where slope overload will take place is						
	Em	$\mathbf{f}_{m}$					
	(a) 0.3 V	8 kHz					
	(b) 1.5 V	4 kHz					
	(c) 1.5 V	2 kHz					
	(d) 3.0 V	1 kHz					
82.	If S represents the carrier synchronization at the receiver and > represents the bandwidth efficiency, then the correct statement for the coherent binary PSK is						
	(a) $\rangle = 0.5$ , S is require	red	(b) $\rangle = 1.0$ , S is requ	(b) $\rangle = 1.0$ , S is required			
	(c) $\rangle = 0.5$ , S is not re	quired	(d) $\rangle = 1.0$ , S is not	required			
83.	A signal is sampled at $8\text{kHz}$ and is quantized using $8\text{-bit}$ uniform quantizer. Assuming SNRq for a sinusoidal signal, the correct statement for PCM signal with a bit rate of R is						
	(a) $R = 32 \text{ kbps}$ , SNR	$R_{q} = 25.8 \text{ dB}$	(b) $R = 64 \text{ kbps}$ , SN	$NR_q = 49.8 \text{ dB}$			
	(c) $R = 64 \text{ kbps}$ , $SNR_q = 64 \text{ kbps}$	= 55.8 dB	(d) $R = 32 \text{ kbps}$ , SN	$NR_q = 49.8 \text{ dB}$			
84.	Medium 1 has the electrical permittivity $\sum_i=1.5 \sum_0$ farad/m and occupies the region						
	to the left of $x=0$ plane. Medium 2 has the electrical permittivity $\Sigma_2=2.5$ $\Sigma_0$ farad/m and occupies the region to the right of $x=0$ plane. If $E_1$ in medium 1 is						
	$ \begin{array}{ccc} E & ( & & \\  & u & \square 3u_y + 1u_y \\  & & 1 & \square 3u_y + 1u_y \end{array} $	) Levolt/m, then E2 in medium	2 is				
	(a) $\left( _{2.0}u_{x}\Box \ 7.5u_{y}+2\right)$	$.5u_z$ ) <sub>vol</sub> t/m	(b) $\left( _{2.0}u_{x}\Box \ 2.0u_{y}+\right.$	$0.6u_z$ $volt/m$			
	(c) $\left( _{1.2}u_{x}\Box \ 3.0u_{y}+1.00\right)$	$(u_z)_{vol}t/m$	(d) $\left( _{1.2}u_{x}\Box \ 2.0u_{y}+\right.$	$0.6u_z$ $v_{ol}t/m$			
85.	If the electric field intensity is given byE= (		)				
	difference between X(a) +1 volt	(20,0) and Y(1,2,3) is (b) -1 volt	$xu_x + yu_y + zu_z volt/n$ (c) +5 volt	n, the potential (d) +6 volt			

A sinusoidal signal with peak-to-peak amplitude of 1.536 V is quantized into 128 levels using a mid-rise uniform quantizer. The quantization noise power is

- 86. A uniform plane wave traveling in air is incident on the plane boundary between air and another dielectric medium with  $\Sigma_r = 4$ . The reflection coefficient for the normal incidence, is
  - (a) zero
- (b) 0.5 180°
- (c)  $0.3330^{\circ}$
- (d) 0.333 180°
- 87. If the electric field intensity associated with a uniform plane electromagnetic wave traveling in a perfect dielectric medium is give by
  - () ( <sup>7</sup>

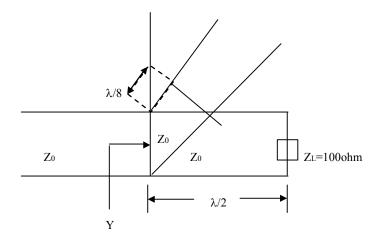
E zt =  $10 \cos 2\square$  · 10 t =  $0.1\square$  z volt/m, then the velocity of the traveling wave

(a)  $3.00 \cdot 10^8$  m/sec

(b)  $2.00 \cdot 10^8$  m/sec

(c)  $6.28 \cdot 10^7$  m/sec

- (d)  $2.00 \cdot 10^7$  m/sec
- 88. A short-circuited stub is shunt connected to a transmission line as shown in Figure. If  $Z_0 = 50$  ohm, the admittance Y seen at the junction of the stub and the transmission line is



(a) (0.01 cm j 0.02) ohm

(b) (0.02 cm j 0.01) ohm

(c) (0.04 œ j0.02) ohm

- (d) (0.02 + j0) ohm
- 89. A rectangular metal wave-guide filled with a dielectric material of relative permittivity  $\Sigma_c = 4$  has the inside dimensions 3.0cm·1.2cm. The cut-off frequency for the dominant mode is
  - (a) 2.5 GHz
- (b) 5.0 GHz
- (c) 10.0 GHz
- (d) 12.5 GHz

